

**Absolute Maximum Ratings** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CES}$	700	V
Collector-Emitter Voltage	$V_{CEO}$	450	V
Emitter-Base Voltage	$V_{EBO}$	9	V
Collector Current	$I_C$	4	A
Peak Collector Current	$I_{CM}$	8	A
Base Current	$I_B$	2	A
Peak Base Current	$I_{BM}$	4	A

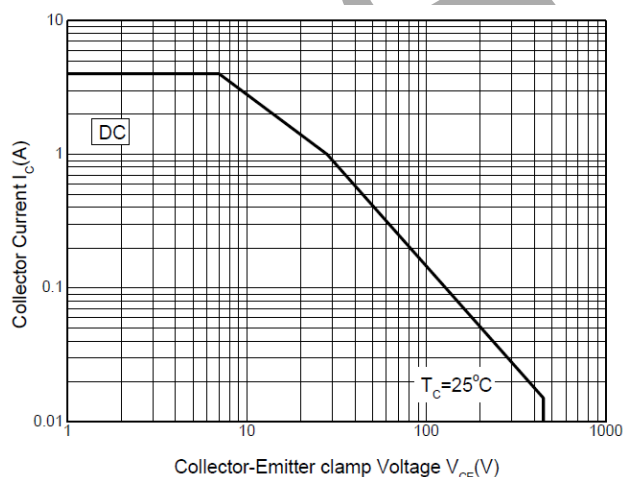
**Thermal Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation @ $T_C = +25^\circ\text{C}$	$P_D$	28	W
		75	
Thermal Resistance, Junction to Case	$R_{\theta JC}$	4.5	$^\circ\text{C/W}$
		1.67	
Operating and Storage Temperature Range	$T_J, T_{STG}$	-65 to +150	$^\circ\text{C}$

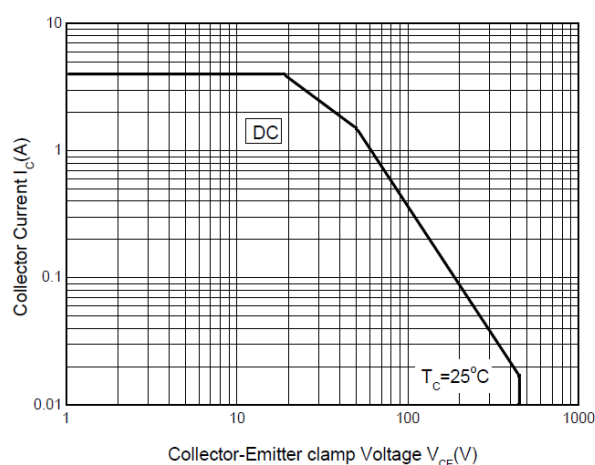
**ESD Ratings** (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	$\geq 8,000$	V	3B
Electrostatic Discharge - Machine Model	ESD MM	$\geq 400$	V	C

Note: 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

**Safe Operating Areas** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)


Safe Operating Areas (TO-220F-3 Package)


 Safe Operating Areas  
 (TO-220-3/TO-220-3(2) Package)

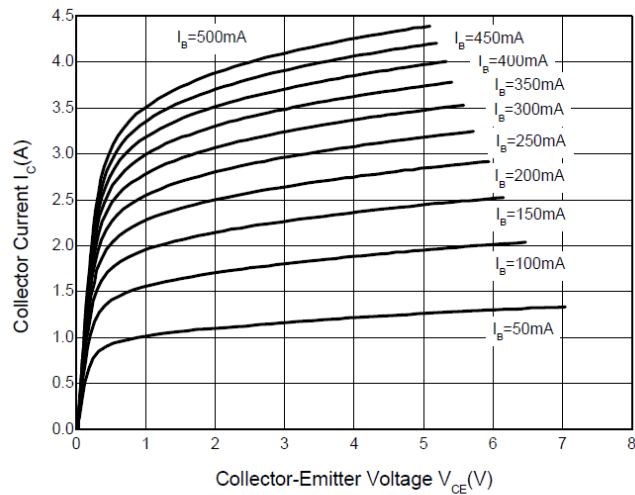
**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	700	—	—	V	I <sub>C</sub> = 100μA, V <sub>BE</sub> = 0V
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	450	—	—	V	I <sub>C</sub> = 100μA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	9	—	—	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CEV</sub>	—	—	10	μA	V <sub>CE</sub> = 700V, V <sub>BE</sub> = -1.5V
DC current transfer Static ratio (Note 5)	h <sub>FE</sub>	15 8	—	35 35	— —	I <sub>C</sub> = 1A, V <sub>CE</sub> = 5V I <sub>C</sub> = 2A, V <sub>CE</sub> = 5V
Collector-Emitter Saturation Voltage (Note 5)	V <sub>CE(sat)</sub>	— — —	— — —	0.3 0.6 0.9	V	I <sub>C</sub> = 1A, I <sub>B</sub> = 0.2A I <sub>C</sub> = 2A, I <sub>B</sub> = 0.5A I <sub>C</sub> = 4A, I <sub>B</sub> = 1A
Base-Emitter Saturation Voltage (Note 5)	V <sub>BE(sat)</sub>	— —	— —	1.1 1.3	V	I <sub>C</sub> = 1A, I <sub>B</sub> = 0.2A I <sub>C</sub> = 2A, I <sub>B</sub> = 0.5A
Output Capacitance	C <sub>ob</sub>	—	45	—	pF	V <sub>CB</sub> = 10V, f = 0.1MHz
Transition Frequency	f <sub>T</sub>	4	—	—	MHz	I <sub>C</sub> = 0.5A, V <sub>CE</sub> = 10V
Turn-on Time with Resistive Load	t <sub>on</sub>	—	—	0.8	μs	I <sub>C</sub> = 2A, V <sub>CC</sub> = 125V I <sub>B1</sub> = -I <sub>B2</sub> = 0.4A
Storage Time with Resistive Load	t <sub>s</sub>	—	—	4.5		
Fall Time with Resistive Load	t <sub>f</sub>	—	—	0.9		

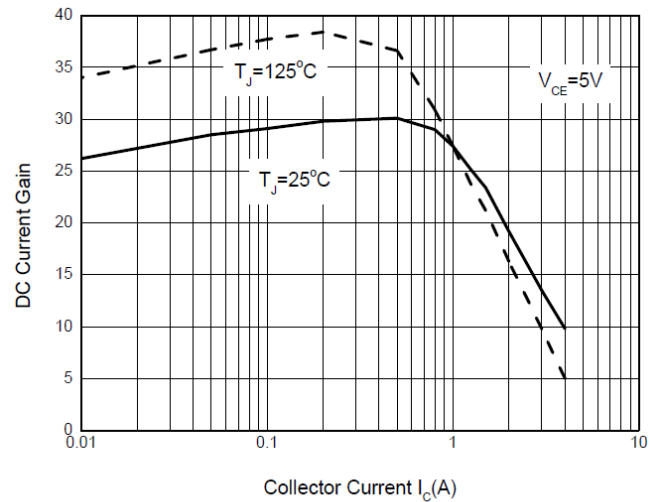
Note: 5. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

OBSOLETE - PART DISCONTINUED

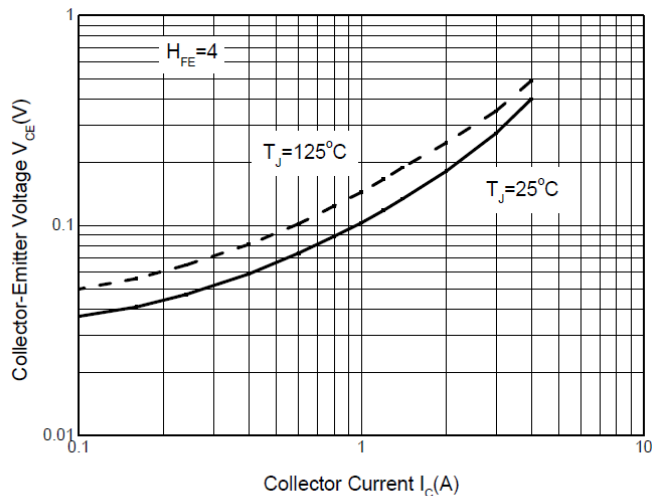
**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



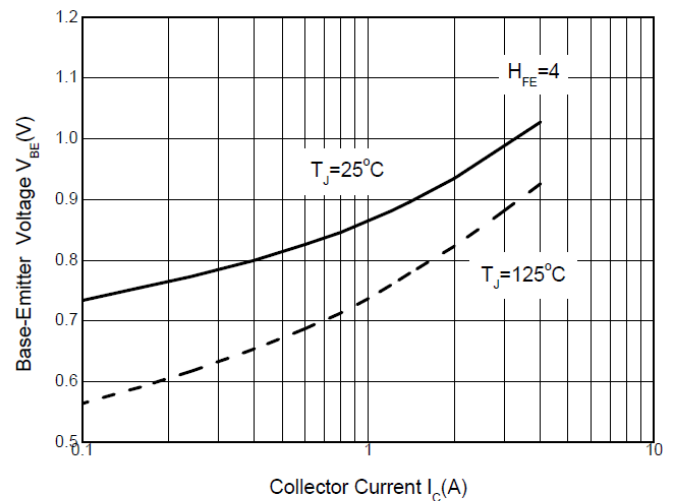
Static Characteristics



DC Current Gain



Collector-Emitter Saturation Region



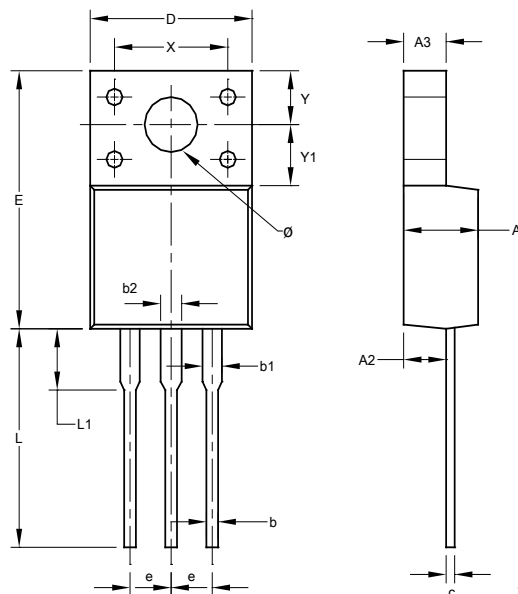
Base-Emitter Saturation Voltage

OBSOLETE - PART DISCONTINUED

# Package Outline Dimensions

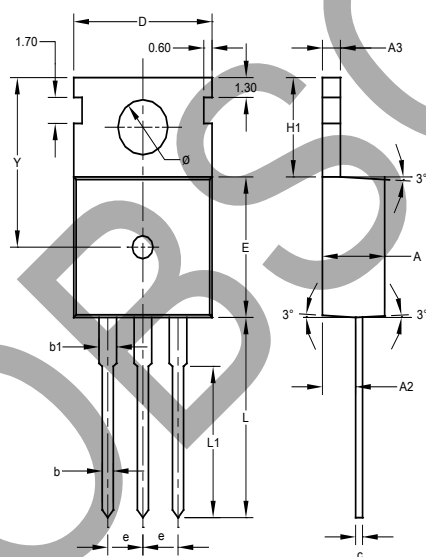
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

## TO220F-3



TO220F-3			
Dim	Min	Max	Typ
A	4.300	4.900	-
A2	2.520	2.920	-
A3	2.350	2.900	-
b	0.550	0.900	-
b1	1.000	1.400	-
b2	1.100	1.500	-
c	0.450	0.600	-
D	9.70	10.30	-
E	14.70	16.00	-
e	-	-	2.540
L	12.50	13.50	-
L1	2.790	4.500	-
X	6.90	7.10	-
Y	3.000	3.400	-
Y1	3.370	3.900	-
ø	3.000	3.550	-
All Dimensions in mm			

## TO220AB Type C (TO220-3(2))



TO220AB Type C			
Dim	Min	Max	Typ
A	-	-	4.500
A2	-	-	2.400
A3	-	-	1.300
b	0.700	0.900	-
b1	-	-	1.270
c	0.400	0.600	-
D	9.800	10.200	-
E	9.000	9.400	-
e	-	-	2.54
H1	6.300	6.700	-
L	12.600	13.600	-
L1	9.600	10.600	-
Y	-	-	11.100
ø	3.560	3.640	-
All Dimensions in mm			

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.

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